



60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C		
co)/	50mΩ @ V _{GS} = 10V	24A		
60V	65mΩ @ V _{GS} = 4.5V	21A		

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

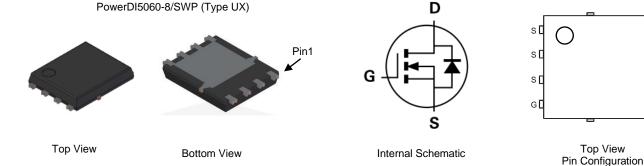
- Engine management systems
- Body control electronics
- DC-DC converters

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes Power Losses
- Low Qg Minimizes Switching Losses
- Wettable Flank for Improved Optical Inspections
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/ An automotive-compliant part is available under separate
 - datasheet (DMNH6042SPSWQ)

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Orderable Part Number	Packago	Packing		
Orderable Part Number	Package	Qty.	Carrier	
DMNH6042SPSW-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information



);; = Manufacturer's Marking NH6042SS = Product Type Marking Code \overline{YY} WW = Date Code Marking \overline{YY} = Year (ex: 24 = 2024) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	60	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 7) V_{GS} = 10V	Steady State	Tc = +25°C T _C = +100°C	ID	24 17	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	35	A
Maximum Continuous Body Diode Forward Current (Note 7)			ls	24	A
Avalanche Current (Note 8) L = 10mH			I _{AS}	3.5	A
Avalanche Energy (Note 8) L = 10mH			Eas	65	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)		Po	1.5	W	
Thermal Desistance, lunction to Ambient (Note 5)	Steady State	5	98	00444	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	Reja	54	°C/W	
Total Power Dissipation (Note 6)		PD	2.9	W	
Thermal Desistance, lunction to Ambient (Note C)	Steady State	5	51	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	Reja	26		
Thermal Resistance, Junction to Case (Note 7)	Rejc	3.5			
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.



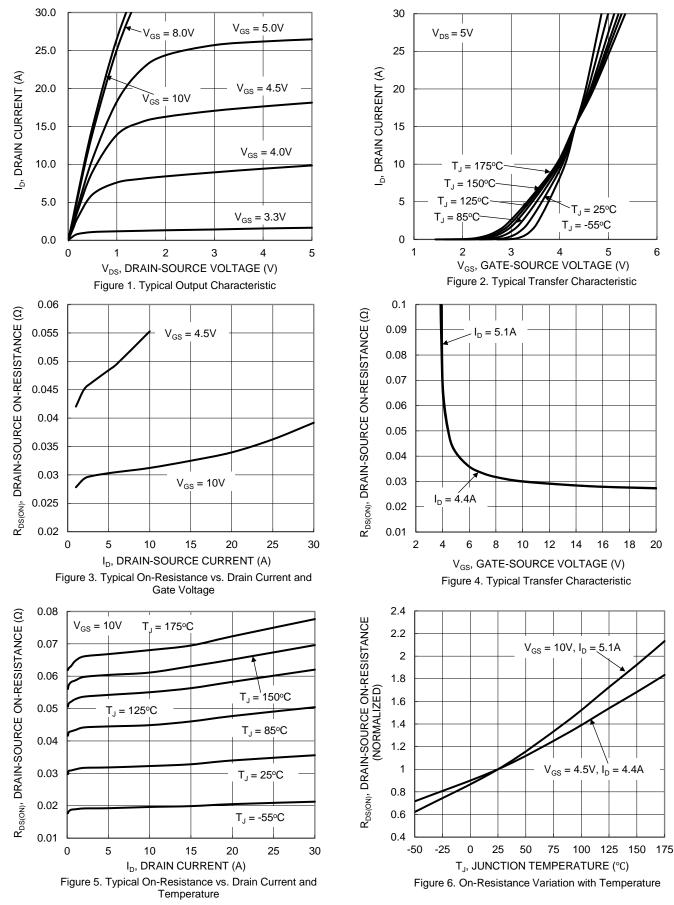
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS		_	1	μA	V _{DS} = 60V, V _{GS} = 0V	
Gate-Source Leakage	lgss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	Vgs(th)	1.0	_	3.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance			34	50	mΩ	$V_{GS} = 10V, I_D = 5.1A$	
Static Drain-Source On-Resistance	RDS(ON)	_	45	65	11122	V _{GS} = 4.5V, I _D = 4.4A	
Diode Forward Voltage	V _{SD}	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 2.6A$	
DYNAMIC CHARACTERISTICS (Note 10)						-	
Input Capacitance	Ciss		584	—	pF		
Output Capacitance	Coss		83	—	pF	Vps = 25V, Vgs = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss		24	—	pF		
Gate Resistance	Rg	_	3.8	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	4.2	—	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	—	8.8	—	nC		
Gate-Source Charge	Qgs	_	1.8	—	nC	$V_{DS} = 44V, I_D = 5.2A$	
Gate-Drain Charge	Qgd	—	1.8	—	nC	1	
Turn-On Delay Time	t _{D(ON)}	_	3.4	_	ns	$V_{GS} = 10V, V_{DS} = 30V,$ $R_G = 6\Omega, I_D = 1A$	
Turn-On Rise Time	tR	_	1.9	_	ns		
Turn-Off Delay Time	tD(OFF)	_	10.1	_	ns		
Turn-Off Fall Time	tF	_	4.5		ns		
Body Diode Reverse-Recovery Time	trr	_	12.9		ns	IF = 2.6A, di/dt = 100A/µs	
Body Diode Reverse-Recovery Charge	Q _{RR}	_	5.4	—	nC	I _F = 2.6A, di/dt = 100A/µs	

Notes: 9. Short duration pulse test used to minimize self-heating effect. 10. Guaranteed by design. Not subject to product testing.

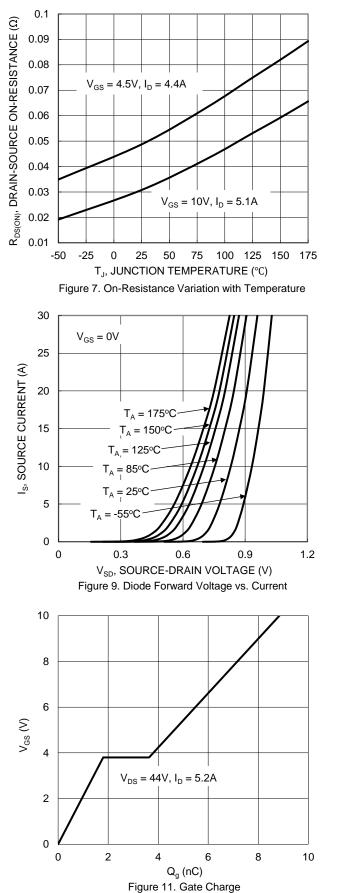


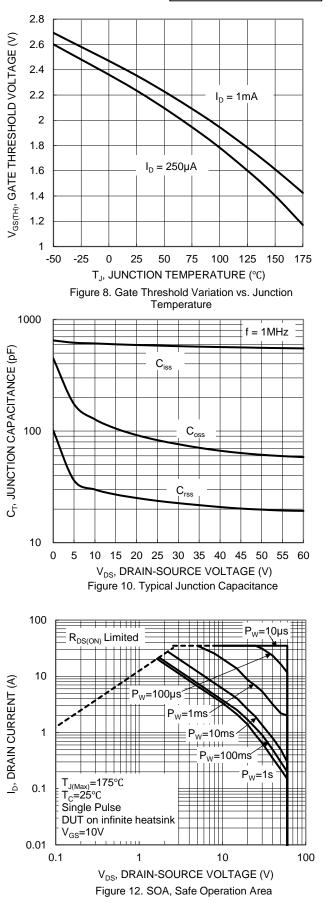
DMNH6042SPSW



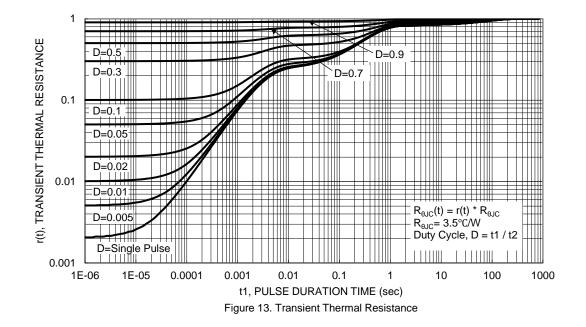


DMNH6042SPSW











PowerDI5060-8/SWP

(Type UX)

Max

1.10

0.05

0.50

0.35

0.25RE

0.330

5.15 BSC

5.10

3.96

4.18

6.00

3.86

4.595

1.27BS(

0.835

0.835

0.400

0.225

4.005

12°

8°

6.40 BS0

Тур

1.00

--

0.41

0.25

0.277

4.90

3.76

3.98

5.80

3.66

4.395

0.735

0.735

0.300

0.125

3.605

11°

7°

Min

0.90

0

0.30

0.20

0.230

4.70

3.56

3.78

5.60

3.46

4.195

1.05

0.635

0.635

0.200

0.025

3.205

10°

6°

All Dimensions in mm

Dim

A A1

b

b2

b4

С

D

D1

D2

D2a

Ε

E1

E2

E2a

е

k

L

La

L1

L4

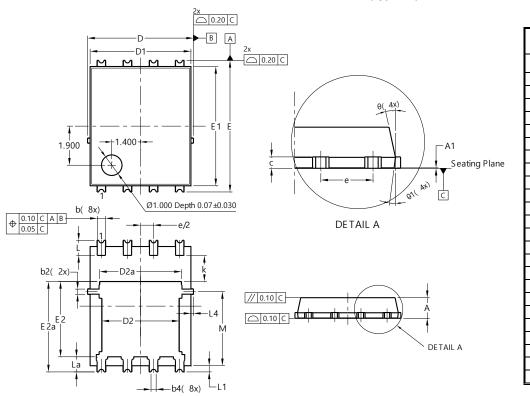
М

θ

θ1

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

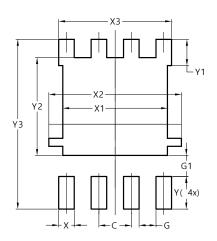


PowerDI5060-8/SWP (Type UX)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	5.190			
X3	4.420			
Y	1.270			
Y1	1.020			
Y2	3.810			
Y3	6.610			



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